What is claimed is:

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1.	A passive	electrical	device	comprising
	11 passive	Olooti lotti	action,	comprising.

a first electrical conductor;

a second electrical conductor disposed over said first electrical conductor;

a third electrical conductor connecting said first electrical conductor to said second electrical conductor, wherein said first, second and third conductors are disposed on a semiconductor substrate and wherein the sheet resistivity of said first electrical conductor is approximately equal to the sheet resistivity of said second electrical conductor.

- 2. The device as claimed in claim 1, wherein each of said first, second and third conductors has a respective thickness, and the thickness of said first conductor is approximately equal to the thickness of said second conductor.
- 3. The device as claimed in claim 1, wherein each of said first, second and third conductors has a respective thickness, the thickness of said first conductor being approximately equal to the thickness of the second conductor and being approximately one-half the thickness of said third conductor.

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4.	The device as claimed in claim 1, wherein said first, second and third
electrical cond	uctors consist essentially of copper.

- 5. The device as claimed in claim 1, wherein said first and third electrical conductors consist essentially of copper, and said second electrical conductor consists essentially of aluminum.
- 6. The device as claimed in claim 1, wherein each of said first and said second electrical conductors has a respective thickness in a range of approximately two to approximately 32 microns.
- 7. The device as claimed in claim 6, wherein said third electrical conductor has a thickness in a range of approximately two to approximately 10 microns.
- 8. The device as claimed in claim 5, wherein said second electrical conductor has a substantially uniform thickness in a range of approximately four microns to approximately six microns.
 - 9. An inductor, comprising:

a semiconductor substrate;

first, second and third electrical conductors provided on said substrate, wherein said first and second electrical